

Claims

[c1]

1. A method for performing an electromigration check for conductors with alternating current flow adjacent to conductors with direct current flow in an integrated circuit comprising:

determining resistances R_{WIRE} and a capacitance matrix \mathbf{C} for the integrated circuit;

converting the capacitance matrix \mathbf{C} into a thermal conductance matrix \mathbf{G} ;

determining temperature differences ΔT_{ni} between conductors from thermal conductances G_{thi} of the thermal conductance matrix \mathbf{G} ;

approximating power flow P_n into conductors with direct current flow due to adjacent conductors with alternating current flow in the integrated circuit from the temperature differences ΔT_{ni} between conductors and the thermal conductances G_{thi} ;

determining a power limit as a function of the maximum temperature difference ΔT_{MAX} that ensures reliability of the integrated circuit; and

performing the electromigration check by limiting power generated in the conductors with alternating current flow to less than the power limit,

wherein n , ni and thi are numerical subscripts that identify parameters as associated with conductor n , conductor n and conductor i , and a thermal characteristic of conductor i , respectively.

[c2]

2. The method of claim 1, wherein the thermal conductance matrix \mathbf{G} is determined from the product of the capacitance matrix \mathbf{C} and a scalar factor F and the scalar factor is given by a ratio of thermal conductivity κ to permittivity ϵ .

[c3]

3.The method of claim 1, wherein the power limit is given by the product of scalar factor F , the total capacitance C_{ntot} and the maximum temperature difference ΔT_{MAX} .

[c4]

4.The method of claim 1, wherein the I_{RMS} value is determined by the expression:

$C_{load} * V_{dd} * \text{frequency} * \text{Switching factor}$.

[c5]

5.The method of claim 1, wherein the thermal conductances G_{thi} are inputs for a circuit simulator that determines temperature differences between conductors ΔT_{ni} as outputs of the circuit simulator.

[c6]

6.The method of claim 1, wherein the capacitance matrix C and resistances R_{WIRE} are determined by using simulation and analysis tools that include capacitance/resistance extraction capabilities.

[c7]

7.A method for performing an electromigration check for conductors with alternating current flow adjacent to conductors with direct current flow comprising:

determining resistances R_{WIRE} and capacitances C_{ni} for conductors with alternating current flow and conductors with direct current flow;

converting the capacitances C_{ni} into thermal conductances G_{thi} ;

determining temperature differences ΔT_{ni} between conductors from the thermal conductances G_{thi} ;

approximating power flow P_n into conductors with direct current flow due to adjacent conductors with alternating current flow from the temperature differences ΔT_{ni} between conductors and thermal conductances G_{thi} ;

determining a power limit as a function of a maximum temperature difference ΔT_{MAX} for the conductors that ensures reliability of the conductor; and

performing the electromigration check by limiting power generated in the conductors with alternating current flow to less than the power limit,
wherein n , n_i and t_{hi} are numerical subscripts that identify parameters as associated with conductor n , conductor n and conductor i , and a thermal characteristic of conductor i , respectively.

[c8]

8.The method of claim 7, wherein the thermal conductances G_{thi} are determined from the product of the capacitances C_{ni} and a factor F and scalar factor F is given by a ratio of thermal conductivity κ to permittivity ϵ .

[c9]

9.The method of claim 7, wherein the power limit is given by the product of scalar factor F , the total capacitance C_{ntot} and the maximum temperature difference ΔT_{MAX} .

[c10]

10.The method of claim 7, wherein the I_{RMS} value is determined by the expression:

$C_{load} * V_{dd} * \text{frequency} * \text{Switching factor}$.

[c11]

11.The method of claim 7, wherein the thermal conductances G_{thi} are inputs for a circuit simulator that determines temperature differences between conductors ΔT_{ni} as outputs of the circuit simulator.

[c12]

12.The method of claim 7, wherein the capacitances C_{ni} and resistances R_{WIRE} are determined by using simulation and analysis tools that at least include capacitance/resistance extraction capabilities.

[c13]

13.A method for performing a check of local heating in a device comprising:

determining resistances R_{WIRE} and at least one of capacitances C_{ni} and a capacitance matrix C for the device;

determining thermal conductances G_{thi} from the at least one of capacitances C_{ni} and a capacitance matrix C ;

setting a maximum temperature difference ΔT_{MAX} in accordance with electromigration requirements; determining a power limit $F * C_{ntot} * \Delta T_{MAX}$ as a function of the maximum temperature difference ΔT_{MAX} ;

checking each interconnect conductor with an alternating current flow to determine if power generated $I_{RMS} * R_{WIRE}^2$ is less than the power limit $F * C_{ntot} * \Delta T_{MAX}$;

indicating no local heating problem with an interconnect conductor when power generated $I_{RMS} * R_{WIRE}^2$ is less than the power limit $F * C_{ntot} * \Delta T_{MAX}$;

indicating a local heating problem exist with said interconnect conductor when the power generated $I_{RMS} * R_{WIRE}^2$ is equal to or greater than power limit $F * C_{ntot} * \Delta T_{MAX}$ and taking corrective action to reduce the power generated $I_{RMS} * R_{WIRE}^2$; and

continuing to check each interconnect conductor with alternating current flow until all interconnect conductors have a value for power generated $I_{RMS} * R_{WIRE}^2$ less than the power limit $F * C_{ntot} * \Delta T_{MAX}$,

wherein n, ni and thi are numerical subscripts that identify parameters as associated with conductor n, conductor n and conductor i, and a thermal characteristic of conductor I, respectively, F is a scalar factor, and ntot is a numerical subscript identifying a total value of an associated parameter.

[c14]

14.The method of claim 13, wherein the thermal conductances G_{thi} are determined from the product of the capacitances C_{ni} and a factor F and scalar factor F is given by a ratio of thermal conductivity κ to permittivity ϵ .

[c15]

15.The method of claim 13, wherein the power limit is given by the product of scalar factor F, the total capacitance C_{ntot} and the maximum temperature difference ΔT_{MAX} .

[c16]

16.The method of claim 13, wherein the I_{RMS} value is determined by the expression:

$C_{load} * V_{dd} * \text{frequency} * \text{Switching factor}$.

[c17]

17.The method of claim 13, wherein said thermal conductances G_{thi} are inputs for a circuit simulator that determines temperature differences ΔT_{ni} as outputs of the circuit simulator.

[c18]

18.The method of claim 13, wherein the capacitances C_{ni} and resistances R_{WIRE} are determined by using simulation and analysis tools that include capacitance/resistance extraction capabilities.

[c19]

19.A computer-readable medium having a plurality of computer executable

instructions for causing a computer to perform an electromigration check for conductors with alternating current flow adjacent to conductors with direct current flow in an integrated circuit, the computer executable instructions comprising:

instructions for determining resistances R_{WIRE} and a capacitance matrix C for the integrated circuit;

instructions for converting the capacitance matrix C into a thermal conductance matrix G ;

instructions for determining temperature differences ΔT_{ni} between conductors from thermal conductances G_{thi} of the thermal conductance matrix G ;

instructions for approximating power flow P_n into conductors with direct current flow due to adjacent conductors with alternating current flow in the integrated circuit from the temperature differences ΔT_{ni} between conductors and the thermal conductances G_{thi} ;

instructions for determining a power limit as a function of the maximum temperature difference ΔT_{MAX} that ensures reliability of the integrated circuit; and

instructions for performing the electromigration check by limiting power generated in the conductors with alternating current flow to less than the power limit, wherein n , ni and thi are numerical subscripts that identify parameters as associated with conductor n , conductor n and conductor i , and a thermal

characteristic of conductor I , respectively, F is a scalar factor, and n_{tot} is a numerical subscript identifying a total value of an associated parameter.

[c20]

20. The computer readable medium of claim 19, wherein the thermal conductance matrix G is determined from the product of the capacitance matrix C and a scalar factor F and the scalar factor is given by a ratio of thermal conductivity κ to permittivity ϵ .

[c21]

21. The computer readable medium of claim 19, wherein the power limit is given by the product of scalar factor F , the total capacitance C_{ntot} and the maximum temperature difference ΔT_{MAX} .

[c22]

22. The computer readable medium of claim 19, wherein the I_{RMS} value is determined by the expression:

$C_{load} * V_{dd} * \text{frequency} * \text{Switching factor}.$

[c23]

23. The computer readable medium of claim 19, wherein the thermal conductances G_{thi} are inputs for a circuit simulator that determines temperature differences between conductors ΔT_{ni} as outputs of the circuit simulator.